Low cost 100 W sensorless FOC fan motor drive solution





Agenda

- 1 Fan market overview
- The 100 W demo introduction
- 3 Key component highlights
- 4 More support

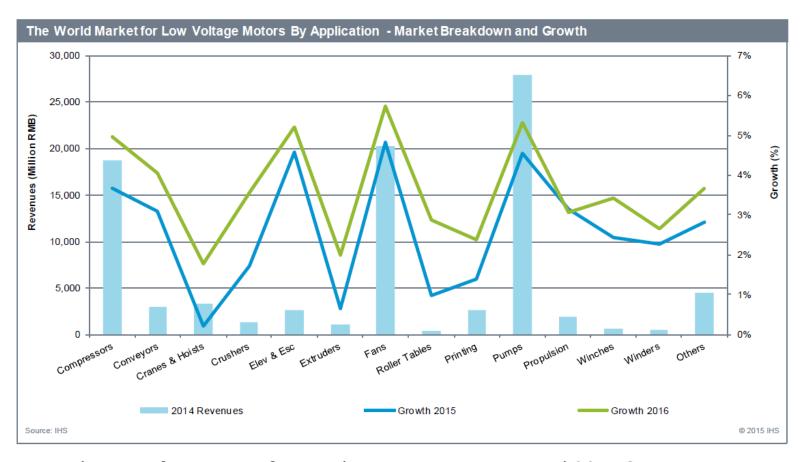


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Pumps, fans and compressors are dominating worldwide motor shipments annually





- Market size for pumps, fans and compressors is around 90BUSD, accounting 75% if worldwide low-voltage motor shipments anually
- > In year of 2014, fans sales revenue is 20BRMB, estimated 6% increase in 2016
- OEMs are being pushed for whole system efficiency improvement

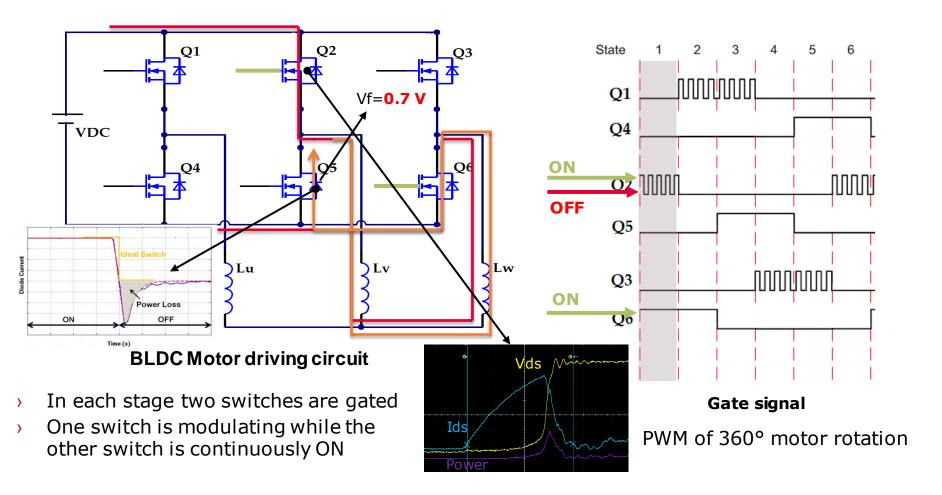


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Big switching loss and reverse current conduct in tradiontal 3 phase half-bridge drive

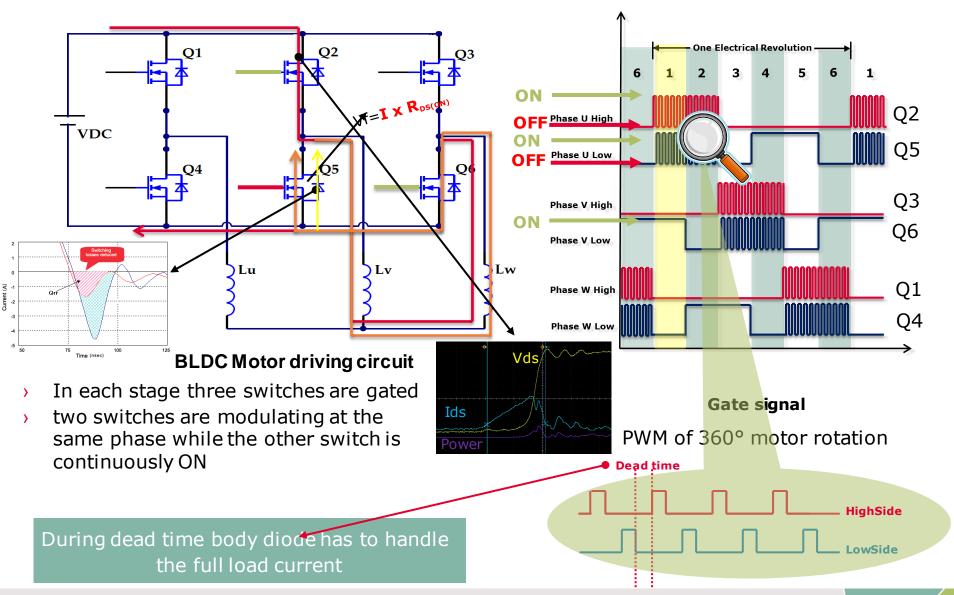




Can we further improve this situation?

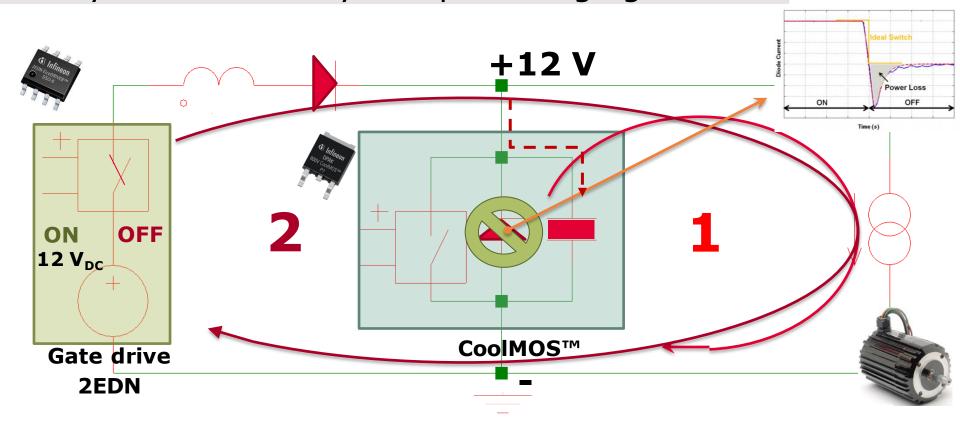
Optimization one: Synchronization to reduce hard communication spikes





New proposed solution Body diode recovery and pre charging circuit

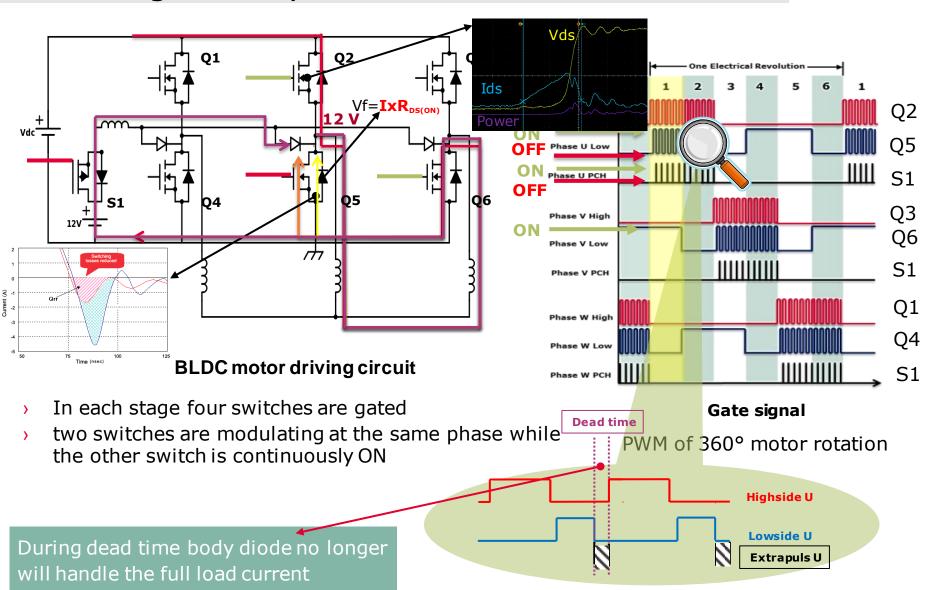




- Current is flowing throw the body diode of the CoolMOS™ at dead time.
- 2. When turning ON S1 the current starts to flow through D2
 - Body diode has 12 V potential (reversed biased)
 - Body diode recovered before turn on of high side switch
 - Part of the current charge the output cap of lowside switch (faster switching)

Optimization two: Precharge and synchronization

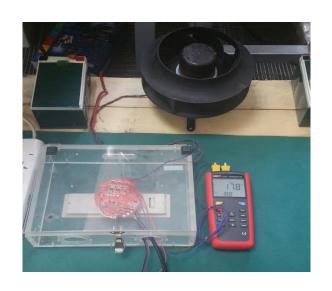






100 W BLDC driver board testing setup

Thermal measurement





Test setup:

- Test conditions:
 - $V_{in}=220 V_{ac}$;
 - No airflow
 - Motor basic spec: phase resistance 14.35 ohm, phase inductance 0.05 H, 2 pole pairs, 3000 rpm, reverse voltage index 105.3 V/Krpm
- Unit initially powered up at 100 W input @1500 RPM of motor speed for long time until MOSFET body temperature is stable before recoding measurement



Stress tests show big margin of CoolMOS™

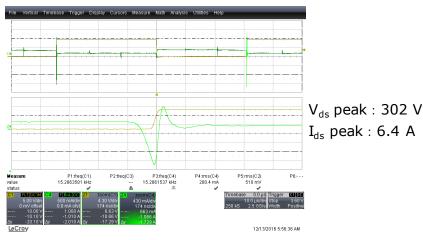
High-side switch

Turn off, V_{ds} and I_{ds} waveform



 V_{ds} peak : 300 V I_{ds} peak : 0.94 A

Turn on, V_{ds} and I_{ds} waveform



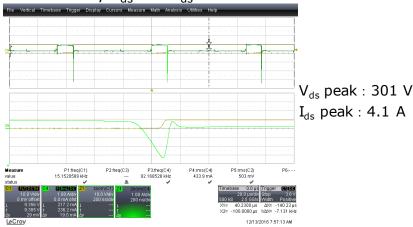
Low-side switch

Turn off, V_{ds} and I_{ds} waveform



 V_{ds} peak : 301 V I_{ds} peak : 1.1 A

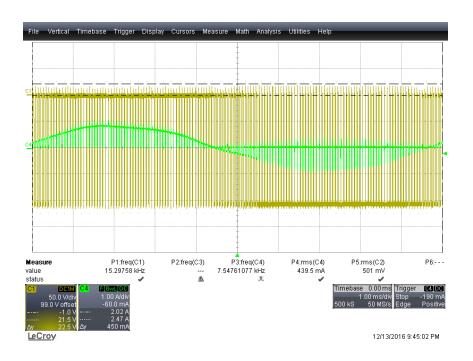






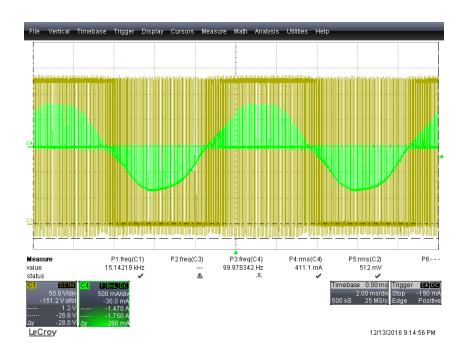
More stress tests

High-side switch



MOS body temperature is 74.6°C

Low-side switch

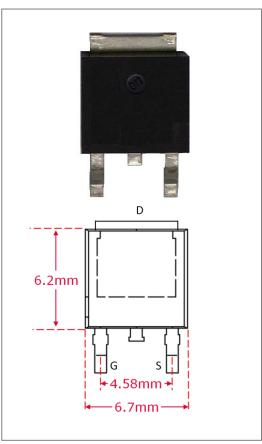


MOS body temperature is 74.1°C

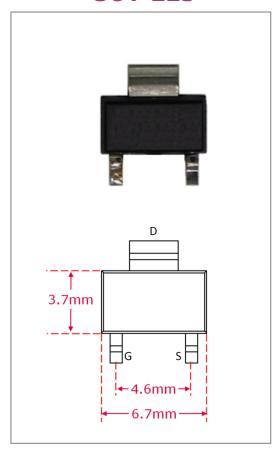
SOT-223 offers smaller footprint while being pin-to-pin compatible with DPAK



DPAK



SOT-223



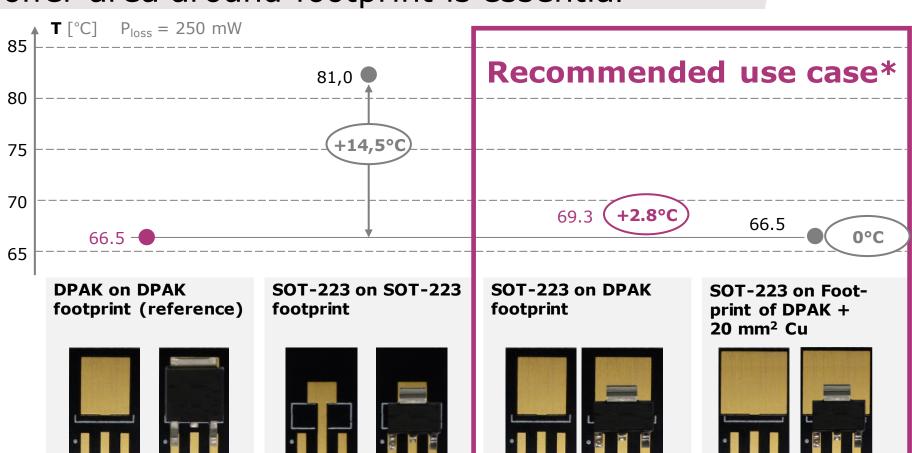
Use cases for SOT-223

- One-on-one
 DPAK replacement for
 reducing cost
- Space savings

 in compact
 designs (thermal limitations,
 please see next
 pages)

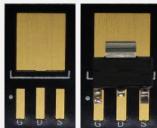
Only slight increase in temperature – add. offer area around footprint is essential





- Replacement for **DPAK**
 - Good for designs with sufficient cooling area

- Good for low power levels
- Footprint savings vs **DPAK**

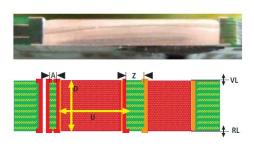


- Drop-in replacement for DPAK
- Good for **designs** with thermal margin

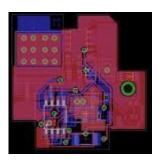


Recommendation for SMD cooling

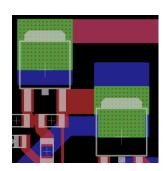
- Concept can follow several methods
 - Copper inlays (production limited and quite expensive concept)
 - Thermal Vias filled with synthetic resin to avoid solder voids at RCdrives Leadframe due to a flow through the vias
 - Small drill holes (between 0.2 and 0.4 mm) for the thermal vias that are filled during galvanization to avoid solder flow
- Infineon recommend the small drill hole concepts since it's the most cost effective solution due to easy production and adequate thermal behavior



Copper Inlays (Ruwel GmbH)



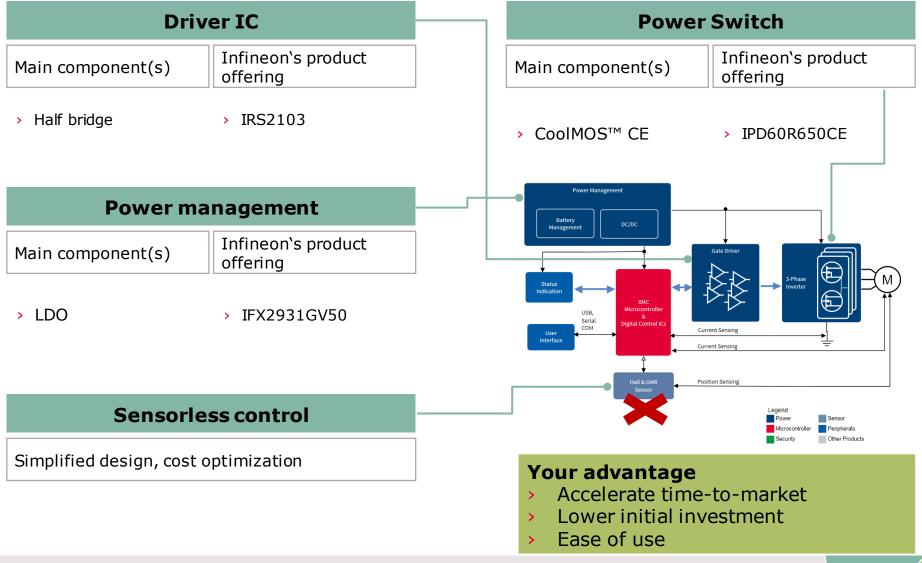
Classical Thermal Vias with resin



Thin-Via-Concept (Small drill holes)

Tested and proven reference design allows better project management to extend success







We can bring more values ...

Value proposition	The solution can provide
Cost & efforts reduction	 Productive solution, save development efforts and cost, fast time to market CoolMOS™ CE used as the replacement of IPM or IGBT, also no need of Hall sensor, can save >10% BOM cost One-stop-shop solution, optimization for purchasing efforts and cost
High efficiency	 Thanks of CoolMOSTM CE lower switching & conductive loss, and with XMC1302 algorithm to reduce reverse current loss, the efficiency improved quite a lot, particularly during light load situation Comparing with discrete IGBT, the CoolMOSTM can reduce body temperature (up to 20°C))
Delivery capacity insurance	 Commonditve components used, esay for purchasing Infineon has the world largest power semi capacity, has 3 front-end sites for silicon manufacturing and >5 back-end plants packaging Flexible multi-source program, improve the business response Fast stock replenishment to shorten CoolMOS™ CE delivery lead time, less than 5weeks
High reliability and quality	 Infineon offers highly ruggedized performance and proven reliability CoolMOS™ offers unrivalled quality in the industry only 38 fails from >1.6 billion shipped parts



Agenda

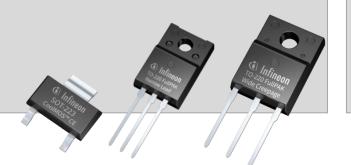
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Infineon addresses customer needs with CoolMOSTM CE on product level & as a supplier



Product benefits of CoolMOS™ CE

- Superjunction MOSFET technology with improved switching
- 2 Better efficiency and thermals
- Innovative packages resulting in BOM cost savings



Benefits from <u>supplier</u> Infineon

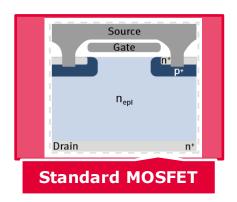
- Supply security from 3 front-end sites (silicon manufacturing) and >5 back-end plants (packaging)
- Unrivalled quality in the industry:
 - Proven track record
 - Highest testing level
- 6 Fast quoting and lead time
 - Multisource business model
 - Fast stock replenishment



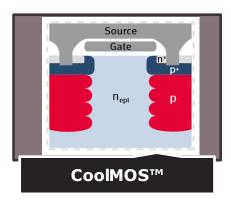
CoolMOS™ CE is a Superjunction MOSFET technolog Headline has to be that offers improved switching and is rapidly growin

24 font size

Planar MOSFET



Superjunction MOSFET



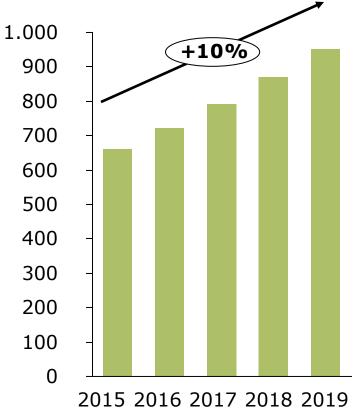
Example 650 V:

$R_{DS(on)}$	1300	1500	$[m\Omega]$
Q_{g^*}	33	10.5	[nC]
$E_{oss^{**}}$	1.6	0.78	[µJ]
C_{oss***}	60	18	[pF]

- Lateral structure
- Larger die size, thus larger capacitance
- Higher switching loss

- Vertical structure
- > Smaller die size, thus smaller capacitance
- Lower switching loss

Superjunction MOSFET forecast (mio USD, Yole Développement)



Better switching vs. planar (conventional) FET

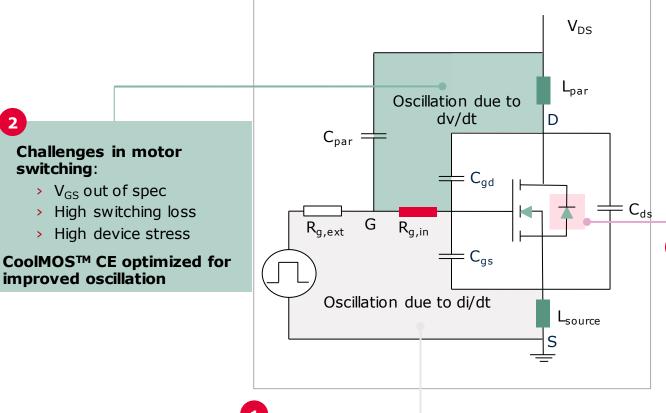
Rapid growth projected



Optimization for ease of use and addresses typical design challenges



Design challenges and value offered by CoolMOS™ CE



3

Challenges in motor drive Body diode hard commutation

- > High voltage overshoot
- High current spike
- > High device stress

CoolMOS™ CE with good commutation ruggedness

Challenges from fast switching:

> EMI and oscillations from high di/dt

CoolMOS™ CE with good controllability for ease-of-use

 $L_{\text{par:}}$ layout parasitic inductance C_{par} : layout parasitic capacitance

CoolMOS™ CE brings a package innovation addressing consumer markets – selected examples

Headline has to be 24 font size

IPAK SL mold stopper	 Defined stand-off between package body and PCB Higher production yield as no residue after cleaning
TO-220 FullPAK Narrow Lead	 Reduced stand-off height Lower height for semi slim adapters as MOSFET can be fully inserted into the PCB
TO-220 FullPAK Wide Creepage	 Increased creepage distance (4.25 vs. 2.54 mm) between legs No arching and no electrical failure even if dust and dirt comes into the power supply
SOT-223	Lower cost DPAK replacementEnabled by smaller dies of superjunction MOSFET

Innovative package solutions...

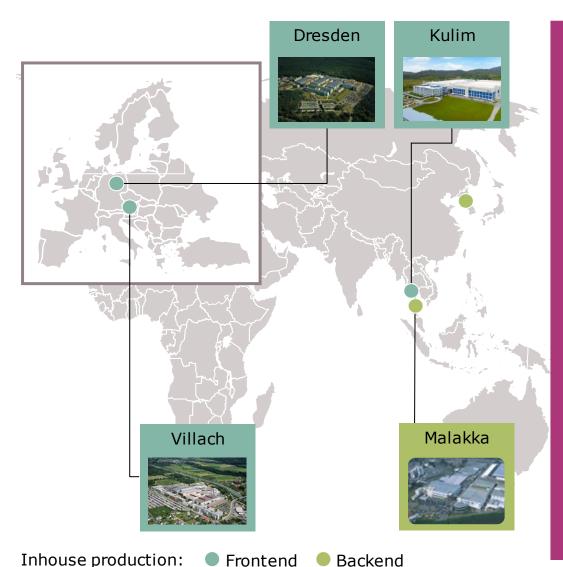


... enable customer BOM savings

4

CoolMOS™ CE offers supply security – production in 3 frontend (silicon) and >5 backend locations (packaging

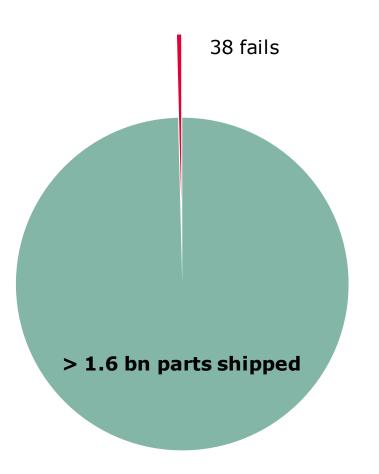
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300 mm (12 inch) production in Dresden



- >World's largest power semicon production facility
- >World's first volume production of power semis on 12"
- State-of-the art equipment from former DRAM maker, highest precision
- CoolMOS™ main volume, flexible upside capacity



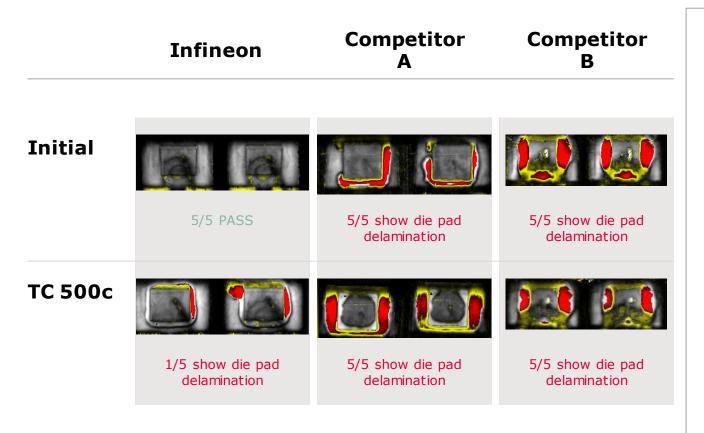
All CoolMOS[™] technologies

- > 0.03 DPM on average
- Only 38 fails over 1.6 bn parts shipped

Quality leadership in power MOSFETs - no other vendor offers such reliable parts

CoolMOS™ offers unrivalled quality in the industry Infineon keeps its quality promise – competitors b

Headline has to be 24 font size



Competitors with large delamination:

- Risk of electrical failure
- Not keeping promised reliability

Infineon invests into high reliability

- Selection of higher grade package
 BOM
- Regular quality monitoring <u>after</u> stressing

Quality leadership in power MOSFETs - no other vendor offers such reliable parts

CoolMOS™ CE offers ease of business via fast quoting and low lead times



Fast quote & price response

- Larger <u>pricing freedom</u> for distributor via multisource price list
- Fast <u>quote response</u> from business manager
 - Target < 24 hrs for >80% requests
 - Up to 3 days in exceptions



Short lead time

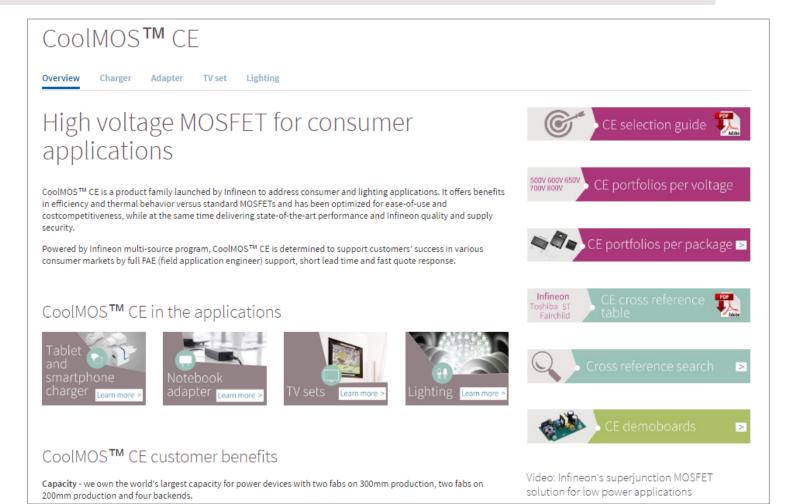


- Faster than normal inventory replenishment to secure certain buffer level
- 4-6 weeks lead time for large orders

Business model for CoolMOS™ CE tailored for speed & ease of business



Where to find more: www.infineon.com/ce



- Product information (parts, selection, x-reference, ...)
- Application information (benefits, demo boards, ...)

32-bit XMC1000 industrial microcontroller ARM® Cortex®-M0





- Core up to 48 MHz/ peripherals up to 96 MHz
- **PWM Timers CCU4**
- 2 serial channels
- 12 Bit ADC
- -40 to 105°C

XMC1200

up to 200 kB Flash / 16-40 pins

XMC1100 up to 64 kB Flash 16-40 pins

9ch LED control 3 analog comparators

>70% **Performance** Increase

XMC1300

up to 200 kB Flash / 16-40 pins

- Math co-processor
- CCU8 PWM timer
- > Hall and encoder I/F

XMC1400

up to 200 kB Flash / 40-64 pins

- > 2x CAN
- 2x CCU8
- Pp to 4 serial channel
- 4x analog converters

TSSOP-16/28/38 - VQFN-24/40/ 64 - LQFP-64

Wide supply voltage range 2.0 V to 5.5 V

Secure boot leader - ensure IP protection

Application specific peripherals

MATH co-processor

ERU Event request unit

High performance analog converters **PWM** timer for motor control (CCU8)

LED brightness color control unit

XMC1000/4000 Motor Control

- beyond standard core...



Dedicated motor control peripherals for various control and feedback schemes

Fast and sophisticated 12-bit ADC (up to 2MSPS)

 Position interfaces for HALL sensors, incremental encoders and resolvers for higher integration

PWM unit tailored for sinusoidal and trapezoidal commutation pattern

Event Request Unit (ERU) enables

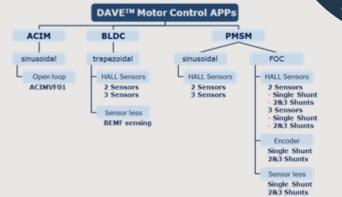
- interconnection between analog, PWM and

- sensor interface peripherals

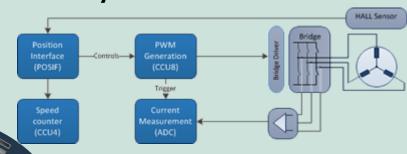
Ideal for FOC control, both low-end and high-performance

DAVE™ APPs support

Comprehensive and growing APPs support for different types of motors and motor control schemes.



Robust and intelligent motor control systems with XMC



BLDC Power Tools Block Diagram

Additional HW/SW features bring your motor control system to the next level:

- Ethernet, CAN, CAN-FD (XMC1400) and serial communication
- Over-current protection (OCP) and Overvoltage protection (OVP) with fast reaction times using ADC fast compare mode (150ns conversion time)
- > Over-temperature protection (w/ext. sensors)
- High temperature range (up to 125°C, XMC4000) and automotive grade flash for most robust and reliable systems
- Sophisticated PWMs allow additional synchronous rectification to increase system efficiency



Motor Control

XMC1000 highlighted feature for motor FOC control



MATH coprocessor

- 38x faster sine, cosine and arctangent calculations
- High-resolution Park/Inverse Park Transforms at 24-bit in less than 1 μ s
- 7x faster division compared to other ARM® Cortex®-M0 devices

CCU8 PWM

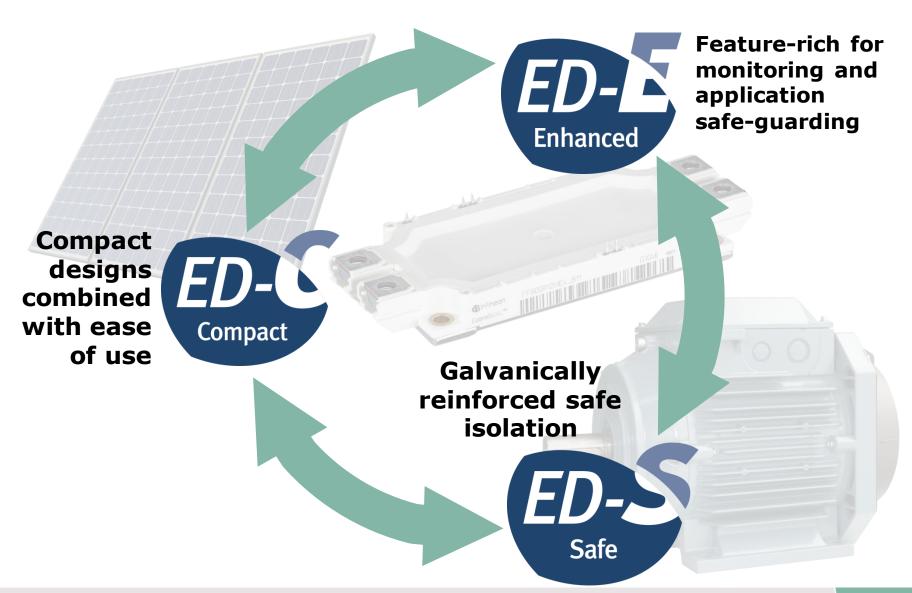
- Generate PWM patterns for all kind of motors
- Interact with ADC for ADC triggering at sensorless control of motors
- Operate always in a safe state even in an error condition
- Dead time control to minimum hardware effort
- 16-bit resolution for high precision space vector PWM generation

ADC

- On-chip ADC gain (x1, x3, x6, or x12) to eliminate external Op-Amp
- Simultaneously sample of multiple analog channels
- Fast ADC reduces torque ripple due to minimized blind angle in sensorless FOC
- Used to sense motor three phase current as feedback to the system



EiceDRIVER™ - your driver solution

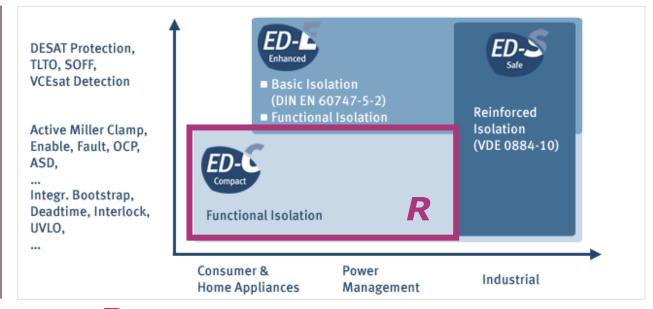


EiceDRIVER™ compact - the right gate driver for all motor drives



- highly reliable driver ICs with functional isolation
- small packages e.g. DSO-8 or TSSOP-28
- offers highest costefficiency & ease-of use
- with Infineon's CorelessTransformer Technology& SOI-Level Shifter

Compact



R recommended for motor drives

Using OptiMOS™ & EiceDRIVER™ C – reduces your system costs by removing ...

- HV bootstrap diode and current limiter
- External comparator and biasing for SC protection
- Enable circuit
- Gate emitter resistors

www.infineon.com/EiceDRIVER™

HV gate drivers a broad, feature-rich portfolio



High Medium Low

Features

1ED-F2 2ED-F2		1ED-F2 2ED-F2			
Gen5	Gen2				
Gen5	Gen2				
6EDL	2EDL	2ED-FI			
Gen5	Gen2				
	1EDI	1EDI			
μHVIC™	1	IEDI			
Driv	es	Galvanic isolated drives			

Level shift driver ICs:

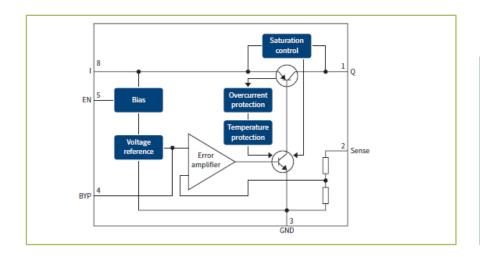
- Gen 2: Mature process, industry benchmark for robustness, broad portfolio up to 1200 V
- Gen 5: Cost effective, feature rich, high accuracy mainly 600 V
- > µHVIC™: SOT-23 building blocks
- 2EDL: Half-Bridge, Silicon on Insulator, integrated bootstrap diode, over current protection (IRIP)
- 6EDL: Three phase, Silicon on Insulator, integrated bootstrap diode

Cordless transformer driver ICs:

1EDI: Single channel, unrivaled output current level, matching propagation delays



Linear voltage regulators for XMC™



Highlights

- Families of linear voltage regulators with fixed or adjustable output voltages
- > Cost optimized ceramic capacitances applicable
- Excellent transient robustness
- Optimized to reject power supply ripples

Key Features

- Supplying up to 500 mA at dropout voltages of below 320 mV
- > Ultra low quiescent current down to 5 μV
- Low noise characteristics

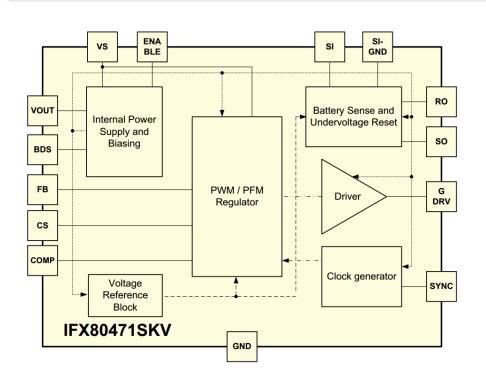
Customer Benefits

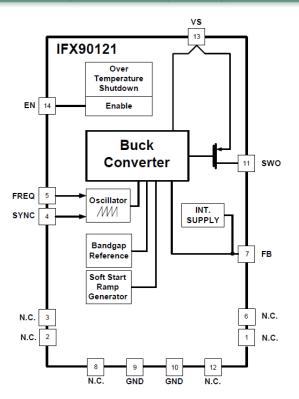
- Highest energy efficiency through ultra low quiescent currents and enable feature – helping to make your control box more efficient
- Space saving through small packages helping to reduce the size of your control box
- Protection mechanisms avoiding system damages
 ensuring safe operations of your motors

DC/DC switching regulators



	Product Class	Туре	Sales Name	Temperature Range	Output Voltage [V]	Output current [A]	Quiescent current [µA]	Maximum Input Voltage [V]	f _{sw} [MHz]	Accuracy Output Voltage [%]	Packages available
ı		DC/DC Controller	IFX80471	-40C to 125C	5,0 / Adj	2.3	2	60	0.36	3	DS014
ı		DC/DC Controller	IFX81481	-40C to 125C	Adj	10	2	45	0.7	2	DS014
ı	Unique	DC/DC Converter	IFX90121	-40 to 125C	5,0	0.5	2	45	2.2	2	SSOP-14
ı		DC/DC Converter	IFX91041	-40C to 125C	3,3 / 5,0 / Adj	1.8	2	45	0.37	2	DSO8-EP







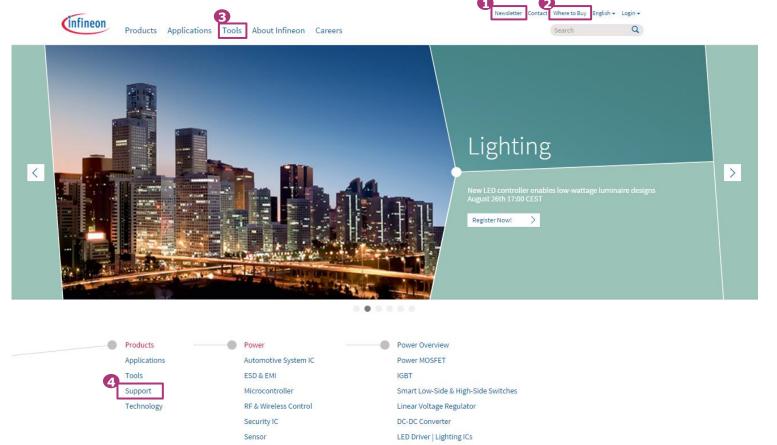
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Support Online tools and services







Smart Card IC

Transistor & Diode

Interface

News & Tweets

Subscribe to Newsletter

Where to Buy

Tools, Finders and Selectors

Support

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Silicon Carbide (SiC)

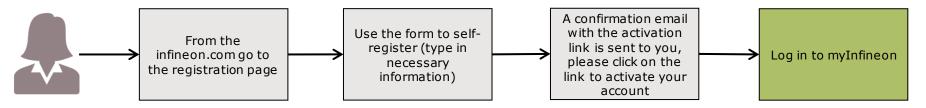
AC-DC Supply

High Power Thyristors & Diodes

Motor Control & Gate Driver



Tailor made information via myInfineon





In case of problems with the access, the registration or all other type of issues, please get in touch with your Infineon contact person or with our official support at www.infineon.com/support (available 24/7)



Part of your life. Part of tomorrow.

